

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	139	(substrate or carrier or base or plate) same (gate near electrode) and (gate near (insulat\$4 or dielectric or oxide)) same (gate near electrode) and (source same (gate near (insulat\$4 or dielectric or oxide))) and (drain same(gate near (insulat\$4 or dielectric or oxide))) and (organic near9 semiconductor) and passivat\$4 and parylene	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 12:08
L2	15	(substrate or carrier or base or plate) same (gate near electrode) and (gate near (insulat\$4 or dielectric or oxide)) same (gate near electrode) and (source same (gate near (insulat\$4 or dielectric or oxide))) and (drain same(gate near (insulat\$4 or dielectric or oxide))) and (organic near9 semiconductor) and passivat\$4 same parylene	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 12:09
L3	14	(substrate or carrier or base or plate) same (gate near electrode) and (gate near (insulat\$4 or dielectric or oxide)) same (gate near electrode) and (source same (gate near (insulat\$4 or dielectric or oxide))) and (drain same(gate near (insulat\$4 or dielectric or oxide))) and (organic near9	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 12:09

		semiconductor) and passivat\$4 same parylene and transistor				
L4	4504	(organic near semiconductor) near (film or layer)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:02
L5	1285	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:03
L6	1101	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric)) same source	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:03
L7	1097	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric)) same source same drain	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:03
L8	1020	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric)) same source same drain and transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:03
L9	139	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric)) same source same drain and transistor and array	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:03

L10	117	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric)) same source same drain and transistor and array and (hole or via or trench or opening or recess or aperture or groove)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:04
L11	24	(organic near semiconductor) near (film or layer) same (gate near (insulat\$4 or oxide or dielectric)) same source same drain and transistor and array and (hole or via or trench or opening or recess or aperture or groove) and parylene	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:05
L12	400	transistor and (pixel near electrode) same (organic near semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:16
L13	55	transistor and (pixel near electrode) same (organic near semiconductor) and (array near panel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:16
L14	45	transistor and (pixel near electrode) same (organic near semiconductor) and (array near panel) and (contact near hole)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:17
L15	43	transistor and (pixel near electrode) same (organic near semiconductor) and (array near panel) and (contact near hole) and (drain near electrode)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:17

L16	43	transistor and (pixel near electrode) same (organic near semiconductor) and (array near panel) and (contact near hole) and (drain near electrode) and (gate near (insulat\$4 or oxide or dielectric))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:18
L17	27657	(pixel near electrode) same transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:20
L18	197	(pixel near electrode) same transistor same (organic near semiconductor)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:20
L19	34	(pixel near electrode) same transistor same (organic near semiconductor) and parylene	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/09/23 13:20

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